BI

SILICON BRIDGE RECTIFIERS

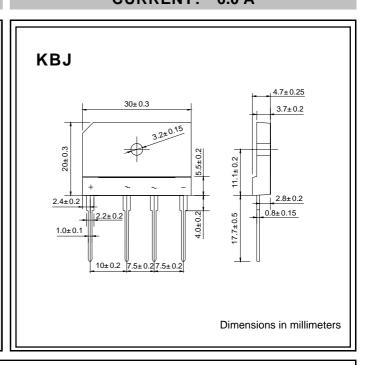
VOLTAGE RANGE: 50 --- 1000 V CURRENT: 6.0 A

FEATURES

- ♦ Rating to 1000V PRV
- ♦ Ideal for printed circuit board
- Reliable low cost construction utilizing molded plastic technique results in inexpensive product
- ♦ Lead solderable per MIL-STD-202 method 208

MECHANCAL DATA

- ♦ Polarity:Symbols molded on body
- ♦ Weight: 0.23 ounces, 6.6 grams



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 ℃ ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

| | | KBJ 6A | KBJ 6B | KBJ 6D | KBJ 6G | KBJ 6J | KBJ 6K | KBJ 6M | UNITS |
|---|--------------------|------------|-----------|-----------|-----------|-----------|-----------|-----------|---------------|
| Maximum recurrent peak reverse voltage | V_{RRM} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| Maximum RMS voltage | V_{RMS} | | 70 | 140 | 280 | 420 | 560 | 700 | V |
| Maximum DC blocking voltage | V_{DC} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| Maximum average forw ard Output current @T _A =110℃ | I _{F(AV)} | 6.0 | | | | | | | А |
| Peak forw ard surge current 8.3ms single half-sine-w ave superimposed on rated load | I _{FSM} | 150.0 | | | | | | | А |
| Maximum instantaneous forw ard voltage at 3.0 A | V _F | 1.0 | | | | | | | V |
| Maximum reverse current @T _A =25℃ | | 10.0 | | | | | | | μA |
| at rated DC blocking_voltage _@T _A =100℃ | I _R | 1.0 | | | | | | | mΑ |
| Typical junction capacitance per element | CJ | 55 | | | | | | | pF |
| Typical thermal resistance | $R_{\theta JC}$ | 1.8 | | | | | | | C/W |
| Operating junction temperature range | TJ | - 55 + 150 | | | | | | | C |
| Storage temperature range | T _{STG} | - 55 + 150 | | | | | | | ${\mathbb C}$ |

NOTES:1. Measured at 1.0MH, and applied reverse voltage of 4.0V DC

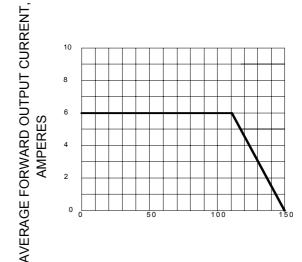
2. Device mounted on 300mm X 300mm X 1.6mm cu Plate heatsink.

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FIG.1 - PEAK FORWARD SURGE CURRENT

NUMBER OF CYCLES AT 60Hz

FIG.2 -- FORWARD DERATING CURVE



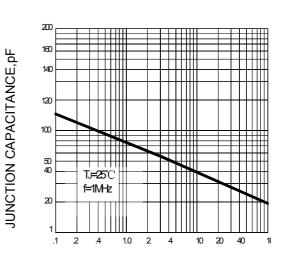
AMBIENT TEMPERATURE, °C

FIG.3 - TYPICAL FORWARD CHARACTERISTIC

100 10 3 1.0 0.1 0.1 .2 .4 .6 .8 1.0 1.2 1.4 1.6

INSTANTANEOUS FORWARD VOLTAGE, VOLTS

FIG.4 - TYPICAL JUNCTION CAPACITANCE



REVERSE VOLTAGE, VOLTS

INSTANTANEOUS FORWARD CURRENT,

AMPERES